

# NCE N-Channel Enhancement Mode Power MOSFET

#### Description

The NCE01H10 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

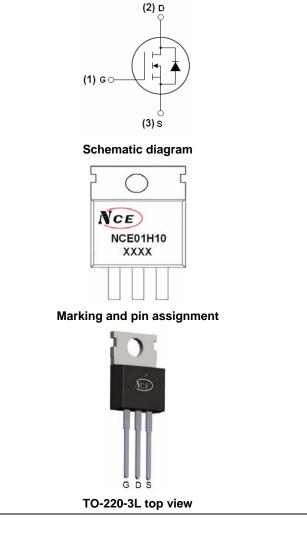
- V<sub>DS</sub> = 100V,I<sub>D</sub> =100A
  R<sub>DS(ON)</sub> < 13mΩ @ V<sub>GS</sub>=10V (Typ:9.9mΩ)
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

#### Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

**100% ΔVds TESTED!** 



#### Package Marking and Ordering Information

	Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
Ī	NCE01H10	NCE01H10	TO-220-3L	-	-	-

#### Absolute Maximum Ratings (T<sub>c</sub>=25℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit	
Vds	Drain-Source Voltage	100	V	
Vgs	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	100	А	
l <sub>D</sub> (100℃)	Drain Current-Continuous(TC=100°C)	80	А	
I <sub>DM</sub>	Pulsed Drain Current	380	А	
PD	Maximum Power Dissipation	200	W	
	Derating factor	1.33	W/℃	
E <sub>AS</sub>	Single pulse avalanche energy (Note 5)	800	mJ	
$T_{J}, T_{STG}$	Operating Junction and Storage Temperature Range	-55 To 175	°C	



**Pb Free Product** 

NCE01H10

#### **Thermal Characteristic**

R <sub>θJC</sub> Thermal Resistance, Junction-to-Case (Note 2)0.75°C/
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#### Electrical Characteristics (T<sub>c</sub>=25°C unless otherwise noted)

	Symbol Para	ameter	Condition	Min	Тур	Max	Unit
Off Characterist	ics						
BV <sub>DSS</sub>	Drain-Source Breakdown	Voltage	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	100	110	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain (	Current	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Cu	Gate-Body Leakage Current		-	-	±100	nA
On Characterist	ics (Note 3)						
V <sub>GS(th)</sub>	Gate Threshold Voltag	ge	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
R <sub>DS(ON)</sub>	Drain-Source On-State Res	sistance	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	-	9.9	13	mΩ
<b>g</b> <sub>FS</sub>	Forward Transconducta	ance	V <sub>DS</sub> =50V,I <sub>D</sub> =40A	100	-	-	S
Dynamic Charac	cteristics (Note4)			•			
C <sub>lss</sub>	Input Capacitance			-	4800	-	PF
C <sub>oss</sub>	Output Capacitance	;	$V_{DS}$ =50V, $V_{GS}$ =0V,	-	340	-	PF
C <sub>rss</sub>	Reverse Transfer Capaci	itance	F=1.0MHz	-	150	-	PF
Switching Chara	acteristics (Note 4)			•			
t <sub>d(on)</sub>	Turn-on Delay Time	9		-	15	-	nS
tr	Turn-on Rise Time		V <sub>DD</sub> =50V,I <sub>D</sub> =40A	-	50	-	nS
t <sub>d(off)</sub>	Turn-Off Delay Time	Э	$V_{GS}$ =10V, $R_{GEN}$ =2.5 $\Omega$	-	40	-	nS
t <sub>f</sub>	Turn-Off Fall Time			-	55	-	nS
Qg	Total Gate Charge		<u>)/ 00)// 404</u>	-	85	-	nC
Q <sub>gs</sub>	Gate-Source Charge	е	$V_{DS}$ =80V,I <sub>D</sub> =40A,	-	18	-	nC
Q <sub>gd</sub>	Gate-Drain Charge		V <sub>GS</sub> =10V	-	28	-	nC
Drain-Source Di	ode Characteristics						
V <sub>SD</sub>	Diode Forward Voltage	Note 3)	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-	-	1.2	V
Is	Diode Forward Current (		-	-	-	57	А
t <sub>rr</sub>	Reverse Recovery Tim	e	TJ = 25°C, IF = 40A	-	38	80	nS
Qrr	Reverse Recovery Char	ge	di/dt = 100A/µs(Note3)	-	53	100	nC
t <sub>on</sub>	Forward Turn-On Time	e	Intrinsic turn-on time is negligible (turn-on is dominated by			y LS+LD)	

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition:Tj=25  $^\circ C$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25\Omega

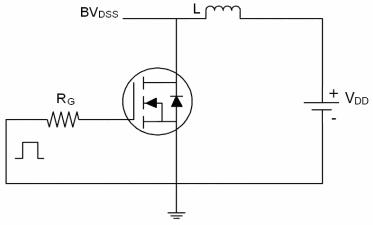


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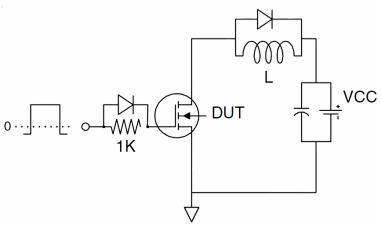




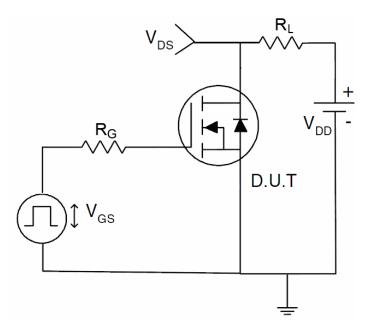
### Test Circuit 1) E<sub>AS</sub> test Circuit



#### 2) Gate charge test Circuit



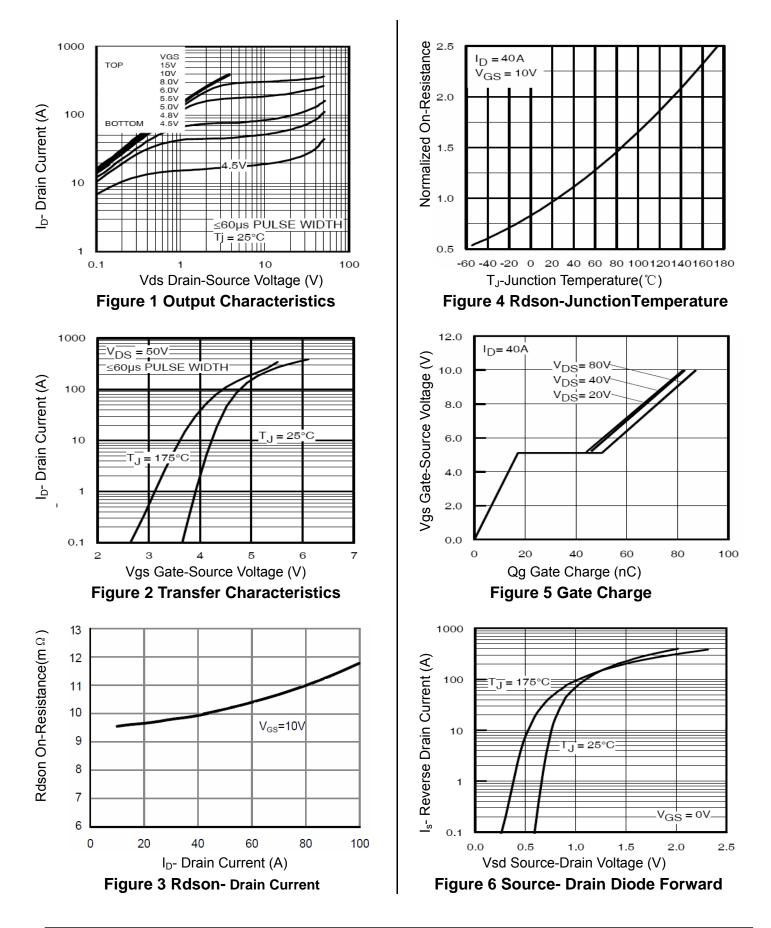
3) Switch Time Test Circuit





# NCE01H10

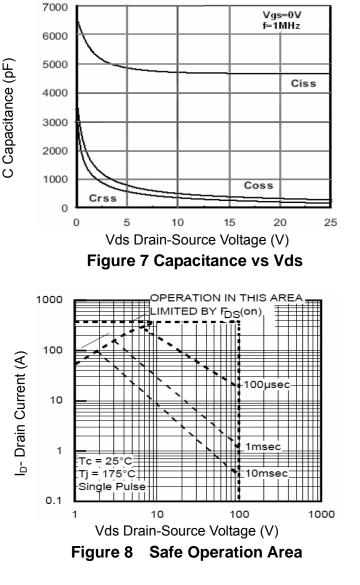
# **Typical Electrical and Thermal Characteristics (Curves)**











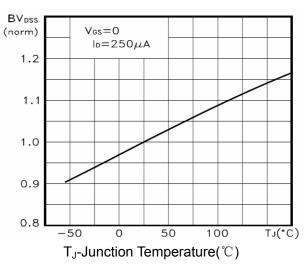


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

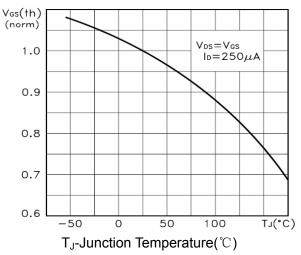
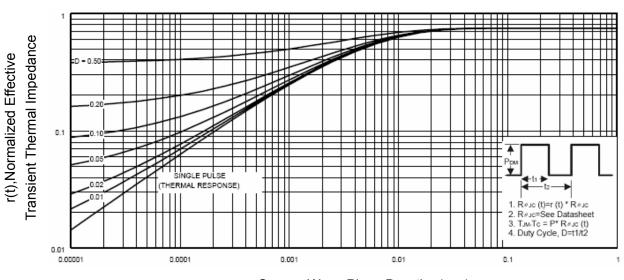


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance

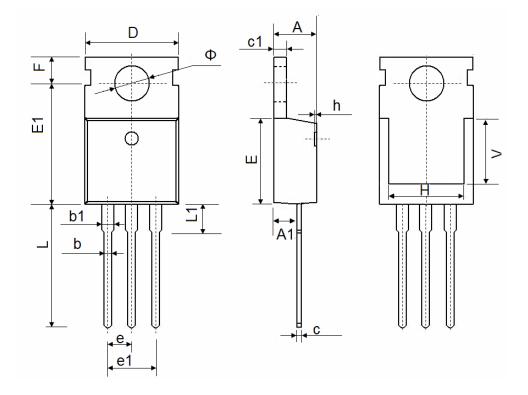
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# TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540	) TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500	) REF.	0.295 REF.		
Φ	3.400	3.800	0.134	0.150	







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